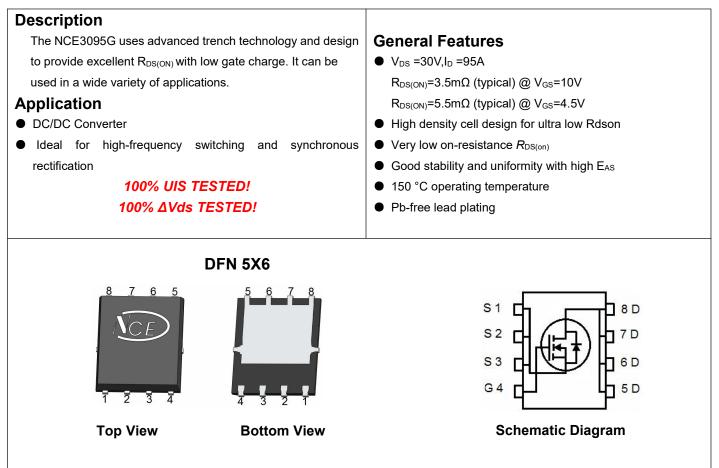


NCE N-Channel Enhancement Mode Power MOSFET



Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCE3095G	NCE3095G	DFN 5x6-8L	-	-	-

Absolute Maximum Ratings (Tc=25°Cunless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	VDS	30	V
Gate-Source Voltage	Vgs	±20	V
Drain Current-Continuous	I _D	95	A
Drain Current-Continuous(Tc=100 ℃)	I _D (100℃)	63.6	А
Pulsed Drain Current	I _{DM}	300	A
Maximum Power Dissipation	PD	80	W
Derating factor		0.64	W/°C
Single pulse avalanche energy (Note 5)	E _{AS}	150	mJ
Operating Junction and Storage Temperature Range	T _J ,T _{STG}	-55 To 150	°C
Thermal Characteristic			
Thermal Resistance, Junction-to-Case ^(Note 2)	Rejc	1.56	°C/W



Electrical Characteristics (TC=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics		1	•			1
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =250µA	30	-	-	V
Zero Gate Voltage Drain Current	IDSS	V _{DS} =30V,V _{GS} =0V	-	-	1	μA
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±20V,V _{DS} =0V	-	-	±100	nA
On Characteristics (Note 3)			•			
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} ,I _D =250µA	1	1.5	2.5	V
Drain Course On State Desistance		V _{GS} =10V, I _D =20A	-	3.5	4.4	- mΩ
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =4.5V, I _D =20A	-	5.5	7.5	
Forward Transconductance	G FS	V _{DS} =5V,I _D =20A	30	-	-	S
Dynamic Characteristics (Note4)			•			
Input Capacitance	Clss	- V _{DS} =15V,V _{GS} =0V,	-	1784	-	PF
Output Capacitance	Coss		-	266	-	PF
Reverse Transfer Capacitance	C _{rss}	F=1.0MHz	-	212	-	PF
Switching Characteristics (Note 4)						
Turn-on Delay Time	t _{d(on)}		-	7	-	nS
Turn-on Rise Time	tr	V _{DD} =5V,I _D =20A	-	6	-	nS
Turn-Off Delay Time	t _{d(off)}	V _{GS} =10V,R _{GEN} =6Ω	-	30	-	nS
Turn-Off Fall Time	t _f		-	8	-	nS
Total Gate Charge	Qg	V 45V/L 00A	-	38.4	-	nC
Gate-Source Charge	Q _{gs}	- V _{DS} =15V,I _D =20A, - V _{GS} =10V	-	5.8	-	nC
Gate-Drain Charge	Q _{gd}	VGS-10V	-	7.9	-	nC
Drain-Source Diode Characteristics	·	·				
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _S =20A	-	0.85	1.2	V
Diode Forward Current (Note 2)	ls		-	-	95	Α
Reverse Recovery Time	trr	TJ = 25°C, I _F = 20A	-	-	47	nS
Reverse Recovery Charge	Qrr	di/dt = 100A/µs ^(Note3)	-	-	25	nC
Forward Turn-On Time	t _{on}	Intrinsic turn-on time is negligible (turn-on is dominated by LS+LD			y LS+LD)	

Notes:

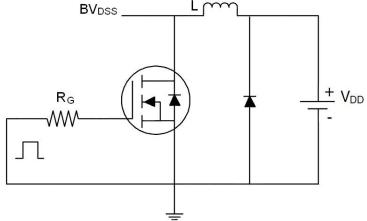
- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- **2.** Surface Mounted on FR4 Board, $t \le 10$ sec.
- **3.** Pulse Test: Pulse Width \leq 300µs, Duty Cycle \leq 2%.
- 4. Guaranteed by design, not subject to production
- **5.** EAS condition: $Tj=25^{\circ}C$, $V_{DD}=15V$, $V_{G}=10V$, L=0.1mH, $Rg=25\Omega$



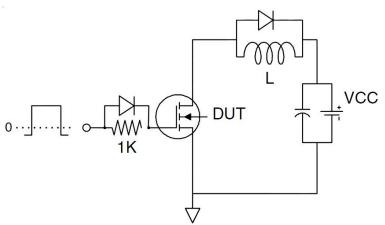
http://www.ncepower.com

Test Circuit

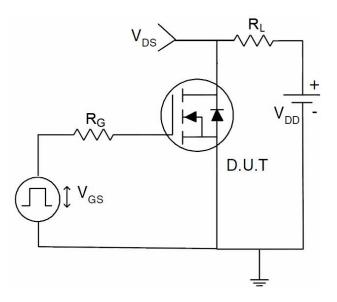
1) E_{AS} Test Circuits



2) Gate Charge Test Circuit



3) Switch Time Test Circuit

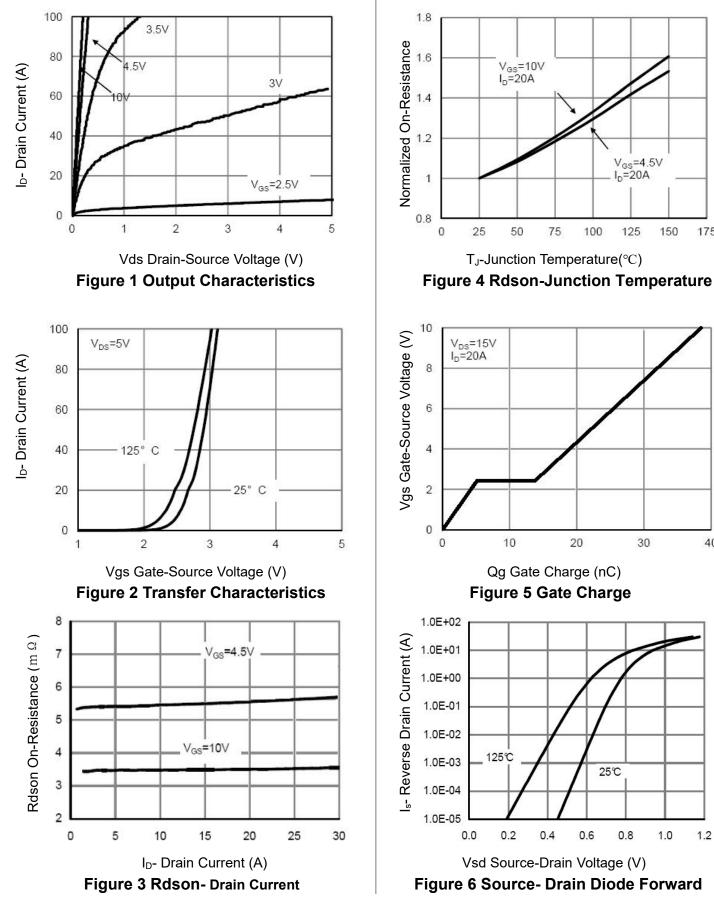




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Typical Electrical and Thermal Characteristics (Curves)

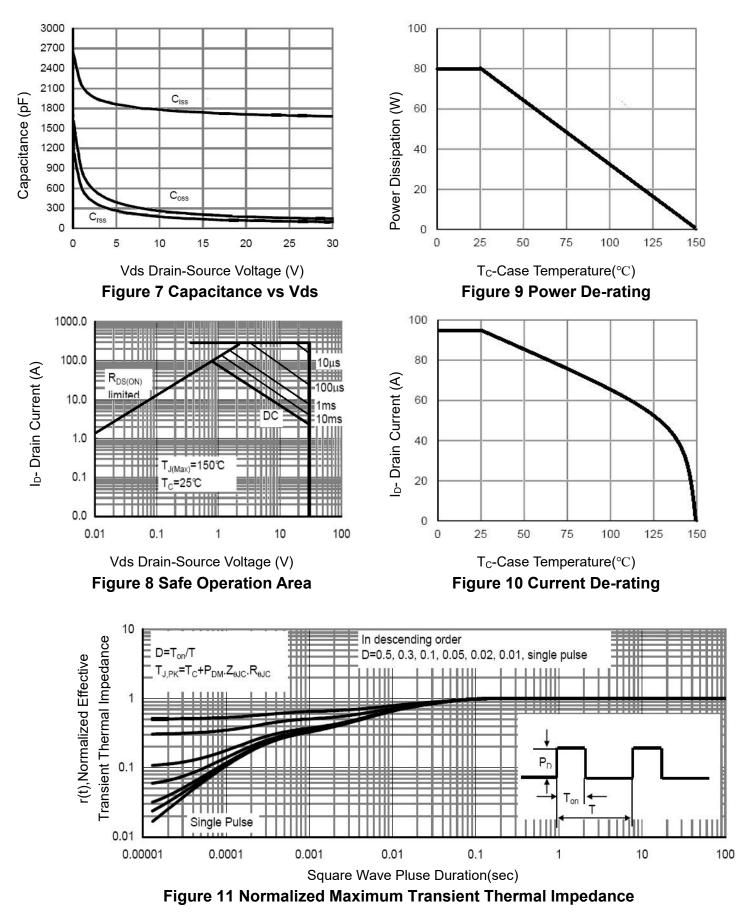


1.2



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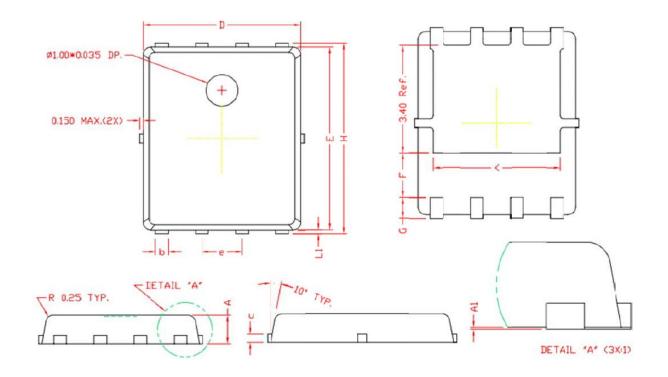
NCE3095G





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DFN5X6-8L Package Information



COMMON DIMENSIONS

(UNITS OF MEASURE=MILLIMETER)

SYMBOL	MIN	NOM	MAX	
А	0.80	0.90	1.00	
A1	0.00	0.03	0.05	
b	0.35	0.42	0.49	
С	0.254 REF.			
D	4.90	5.00	5.10	
F	1.40 REF.			
E	5.70	5.80	5.90	
е	1.27 BSC.			
H	5.95	6.08	6.20	
L1	0.10	0.14	0.18	
G	0.60 REF.			
K	4.00 REF.			



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